NSN 5962-01-490-7415

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-665.0/+150.0 degrees celsius
Features Provided:
Monolithic and electrostatic sensitive and programmable and high power and 3-state output and bidirectional and high performance
Inclosure Material:
Ceramic and plastic
Inclosure Configuration:
Pin grid array
Terminal Surface Treatment:
Gold
Product Name:
Microcircuit, memory, digital, cmos 9000 gate programmable logic array, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Memory Device Type:
Programmable
Special Features:
Generic p/n 3090-100
Precious Material And Location:
Terminals gold
Precious Material:
Gold
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
175 pin
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
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